TECHNICAL DATA DATA SHEET 5478, REV. -

HERMETIC SCHOTTKY RECTIFIER IN SMD-0.2 Very Low Forward Voltage Drop

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings

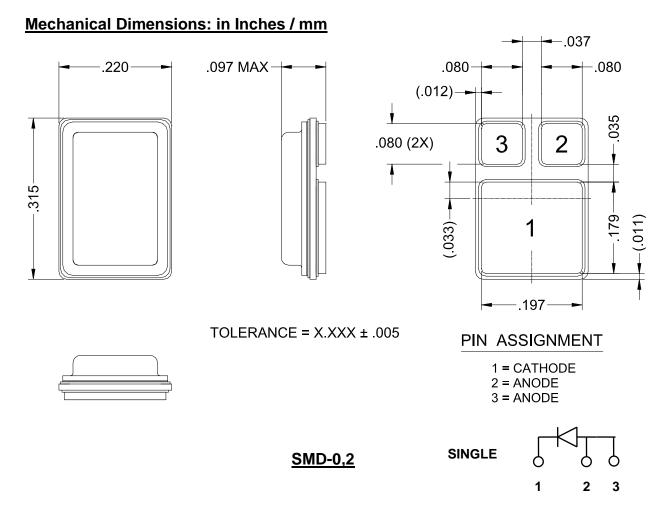
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form (Single)	10	A
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	100	A
Maximum Thermal Resistance	$R_{ ext{ heta}JC}$	-	6.4	°C/W
Max. Junction Temperature	TJ	-	-65 to +150	°C
Max. Storage Temperature	T _{stg}	-	-65 to +150	°C

Electrical Characteristics

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 1A, Pulse, T _J = 25 °C	0.48	V
	V _{F2}	@ 3A, Pulse, T _J = 25 °C	0.56	
	V _{F3}	@ 5A, Pulse, T _J = 25 °C	0.63	
	V _{F4}	@ 7A, Pulse, T ₁ = 25 °C	0.69	
	V _{F5}	@ 10A, Pulse, T _J = 25 °C	0.76	
(per leg)	V _{F6}	@ 1A, Pulse, T _J = 125 °C	0.37	V
	V _{F7}	@ 3A, Pulse, T _J = 125 °C	0.47	
	V _{F8}	@ 5A, Pulse, T _J = 125 °C	0.54	
	V _{F9}	@ 7A, Pulse, T _J = 125 °C	0.59	
	V _{F10}	@ 10A, Pulse, T _J = 125 °C	0.66	
	V _{F11}	@ 1A, Pulse, T _J = - 55 °C	0.57	V
	V _{F12}	@ 3A, Pulse, T _J = - 55 °C	0.63	
	V _{F13}	@ 5A, Pulse, T _J = - 55 °C	0.69	
	V _{F14}	@ 7A, Pulse, T _J = - 55 °C	0.74	
	V_{F15}	@ 10A, Pulse, T _J = - 55 °C	0.80	
Max. Reverse Current	I _{R1}	$@V_R = 100V$, Pulse, T _J = 25 °C	0.2	mA
(per leg)	I _{R2}	@V _R = 100V, Pulse, T _J = 125 °C	20	mA
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	600	pF
(per leg)		$f_{SIG} = 1MHz$, $V_{SIG} = 50mV$ (p-p)		

SENSITRON SEMICONDUCTOR

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